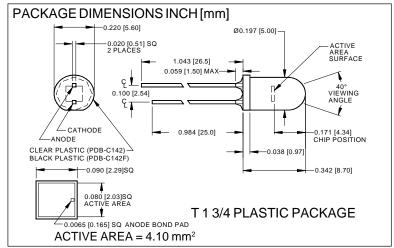
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive **DETECTORS INC.** Type PDB-C142, with daylight filter Type PDB-C142F





FEATURES

- Large active area
- High speed
- Low cost

DESCRIPTION: The **PDB-C142** detector is

a 4.10 mm² planar pin photodiode packaged in a T 1 3/4, water clear plastic housing. Designed for high speed, low capacitance,

photoconductive applications. The **PDB-C142F** includes a daylight filter.

APPLICATIONS

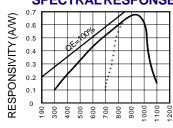
- Smoke detectors
- Light dimmers
- TV & VCR remotes

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
$V_{\mathtt{BR}}$	Reverse Voltage		50	V
T _{STG}	Storage Temperature	-40	+100	∘C
T _o	Operating Temperature Range	-40	+80	∘C
T _s	Soldering Temperature*		+260	∘C
IL	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

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SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS		
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	100	150		μ A		
I _D	Dark Current	$H = 0, V_R = 10 V$		5	30	nA		
R _{SH}	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$	100	500		МΩ		
TCR _{SH}	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/℃		
C _J	Junction Capacitance	$H = 0, V_R = 0 V^*$		18	25	pF		
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm		
λр	Spectral Response - Peak			950		nm		
V _{BR}	Breakdown Voltage	I = 10 μA	15	25		V		
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		2x10 ⁻¹⁴		W/ √Hz		
tr	Response Time	$RL = 1 K\Omega V_p = 10 V$		50		nS		